Triple inverting Schmitt trigger

Rev. 2 — 9 December 2013

Product data sheet

1. General description

The 74HC3G14-Q100; 74HCT3G14-Q100 is a triple inverter with Schmitt-trigger inputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Complies with JEDEC standard no. 7A
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC3G14-Q100: CMOS level
 - For 74HCT3G14-Q100: TTL level
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times
- Multiple package options
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

3. Applications

- Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- Monostable multivibrators



4. Ordering information

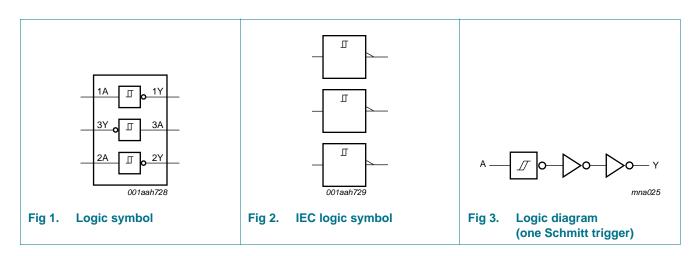
Table 1. Ordering in	nformation				
Type number					
	Temperature range	Name	Description	Version	
74HC3G14DP-Q100	–40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads;	SOT505-2	
74HCT3G14DP-Q100			body width 3 mm; lead length 0.5 mm		
74HC3G14DC-Q100	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8	SOT765-1	
74HCT3G14DC-Q100	-		leads; body width 2.3 mm		

5. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74HC3G14DP-Q100	H14
74HCT3G14DP-Q100	T14
74HC3G14DC-Q100	H14
74HCT3G14DC-Q100	T14

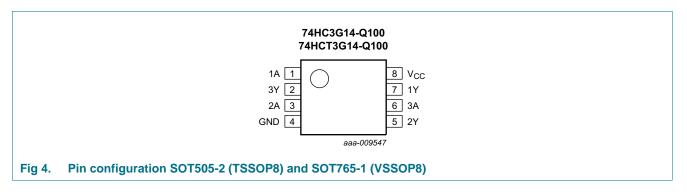
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pi	n description	
Symbol	Pin	Description
1A, 2A, 3A	1, 3, 6	data input
GND	4	ground (0 V)
1Y, 2Y, 3Y	7, 5, 2	data output
V _{CC}	8	supply voltage

8. Functional description

Table 4. Function table^[1]

Input	Output
nA	nY
L	Н
Н	L

[1] H = HIGH voltage level; L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	V_{O} < –0.5 V or V_{O} > V_{CC} + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to V_{CC} + 0.5 V	<u>[1]</u> _	±25	mA
I _{CC}	supply current		<u>[1]</u> _	+50	mA
I _{GND}	ground current		<u>[1]</u> –50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2] _	300	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

For VSSOP8 package: above 110 °C the value of Ptot derates linearly with 8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	ol Parameter Conditions		74HC3G14-Q100			74HCT3G14-Q100			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

11. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at $T_{amb} = 25 \degree$ C.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC3G	14-Q100						•			
V _{OH}	HIGH-level	$V_I = V_{T+} \text{ or } V_{T-}$								
	output voltage	$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_0 = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	4.13	-	3.7	-	V
		$I_0 = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.68	5.81	-	5.63	-	5.2	-	V
V _{OL}	LOW-level	$V_I = V_{T+}$ or V_{T-}								
	output voltage	$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	-	±1.0	-	±1.0	μA
I _{CC}	supply current	per input pin; $V_{CC} = 6.0 V$; $V_I = V_{CC}$ or GND; $I_O = 0 A$;	-	-	1.0	-	10	-	20	μA
CI	input capacitance		-	2.0	-	-	-	-	-	pF
74HCT3	G14-Q100									
V _{OH}	HIGH-level	$V_I = V_{T+}$ or V_{T-}								
	output voltage	$I_{O} = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	4.13	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_0 = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±0.1	-	±1.0	-	±1.0	μA
I _{CC}	supply current	per input pin; $V_{CC} = 5.5 V$; $V_I = V_{CC}$ or GND; $I_O = 0 A$;	-	-	1.0	-	10	-	20	μA
∆l _{CC}	additional supply current	per input; $V_{CC} = 4.5 V \text{ to } 5.5 V;$ $V_I = V_{CC} - 2.1 V; I_O = 0 A$	-	-	300	-	375	-	410	μΑ
Cı	input capacitance		-	2.0	-	-	-	-	-	pF

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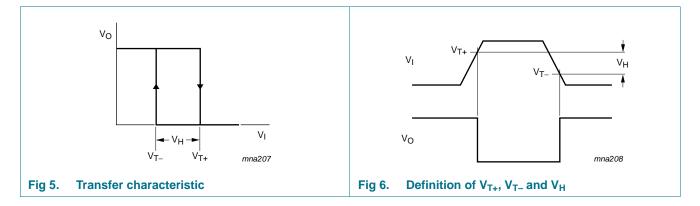
Table 8. Transfer characteristics

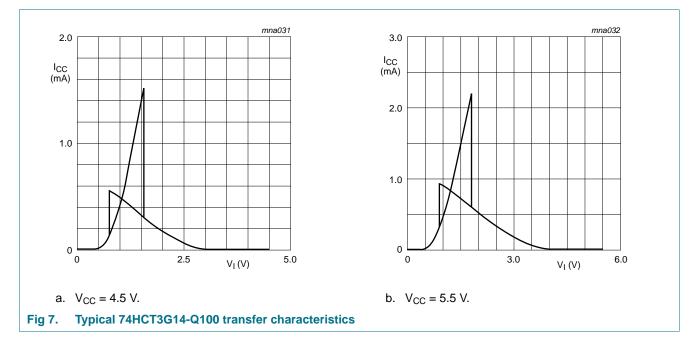
Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 10.

Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HC3G	14-Q100								
V _{T+}	positive-going	see Figure 5, Figure 6							
	threshold voltage	$V_{CC} = 2.0 V$	1.00	1.18	1.50	1.00	1.50	1.50	V
		$V_{CC} = 4.5 V$	2.30	2.60	3.15	2.30	3.15	3.15	V
		$V_{CC} = 6.0 V$	3.00	3.46	4.20	3.00	4.20	4.20	V
V _{T-}	negative-going	see <u>Figure 5</u> , <u>Figure 6</u>							
threshold voltage	$V_{CC} = 2.0 V$	0.30	0.60	0.90	0.30	0.90	0.90	V	
		$V_{CC} = 4.5 V$	1.13	1.47	2.00	1.13	2.00	2.00	V
		$V_{CC} = 6.0 V$	1.50	2.06	2.60	1.50	2.60	2.60	V
V _H hyste	hysteresis voltage	(V _{T+} – V _{T−}); see <u>Figure 5,</u> <u>Figure 6</u> and <u>Figure 8</u>							
		$V_{CC} = 2.0 V$	0.30	0.60	1.00	0.30	1.00	1.00	V
		$V_{CC} = 4.5 V$	0.60	1.13	1.40	0.60	1.40	1.40	V
		$V_{CC} = 6.0 V$	0.80	1.40	1.70	0.80	1.70	1.70	V
74HCT3	G14-Q100								
V _{T+}	positive-going	see Figure 5, Figure 6							
	threshold voltage	$V_{CC} = 4.5 V$	1.20	1.58	1.90	1.20	1.90	1.90	V
		$V_{CC} = 5.5 V$	1.40	1.78	2.10	1.40	2.10	2.10	V
V _{T-}	negative-going	see Figure 5, Figure 6							
	threshold voltage	$V_{CC} = 4.5 V$	0.50	0.87	1.20	0.50	1.20	1.20	V
		$V_{CC} = 5.5 V$	0.60	1.11	1.40	0.60	1.40	1.40	V
V _H	hysteresis voltage	$(V_{T+} - V_{T-})$; see <u>Figure 5</u> , <u>Figure 6</u> and <u>Figure 7</u>							
		$V_{CC} = 4.5 V$	0.40	0.71	-	0.40	-	-	V
		$V_{CC} = 5.5 V$	0.40	0.67	-	0.40	-	-	V

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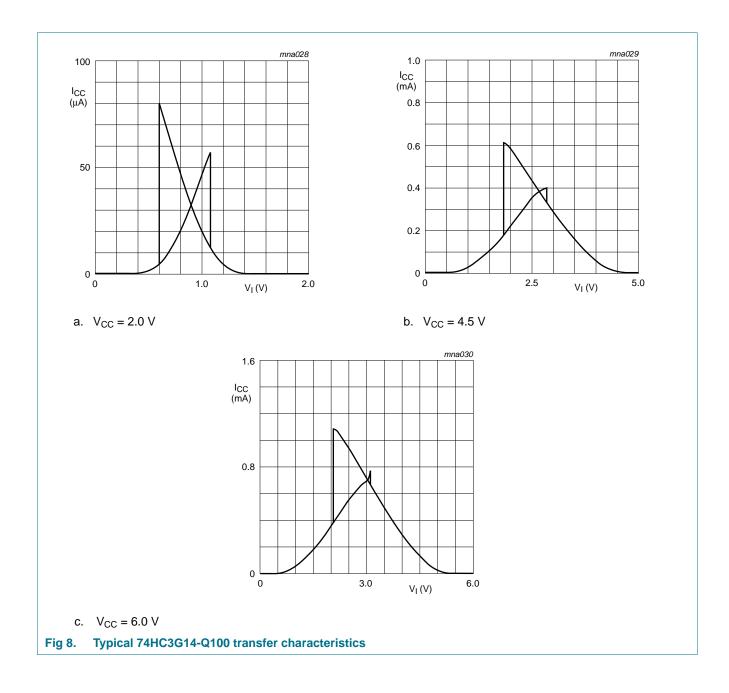






74HC_HCT3G14_Q100

Triple inverting Schmitt trigger



12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 10.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +1	25 °C	Unit
				Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HC3G1	4-Q100									
t _{pd}	propagation delay	nA to nY; see Figure 9	<u>[1]</u>							
		$V_{CC} = 2.0 V$		-	53	125	-	155	190	ns
	$V_{CC} = 4.5 V$		-	16	25	-	31	38	ns	
		$V_{CC} = 6.0 V$		-	13	21	-	26	32	ns
tt	transition time	nY; see <u>Figure 9</u>	[2]							
		$V_{CC} = 2.0 V$		-	20	75	-	95	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	22	ns
		$V_{CC} = 6.0 V$		-	5	13	-	16	19	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	<u>[3]</u>	-	10	-	-	-	-	pF
74HCT30	614-Q100									
t _{pd}	propagation delay	nA to nY; see Figure 9	[1]							
		$V_{CC} = 4.5 V$		-	21	32	-	40	48	ns
t _t	transition time	nY; see <u>Figure 9</u>	[2]							
		$V_{CC} = 4.5 V$		-	6	15	-	19	22	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to $V_{CC}-1.5~V$	<u>[3]</u>	-	10	-	-	-	-	pF

[1] t_{pd} is the same as t_{PLH} and t_{PHL}

[2] t_t is the same as t_{TLH} and t_{THL}

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Triple inverting Schmitt trigger

13. Waveforms

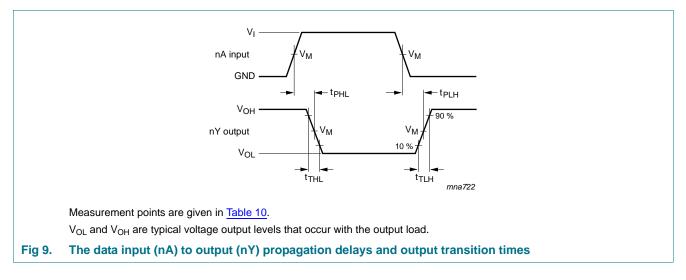


Table 10.Measurement points

Туре	Input	Output
	V _M	V _M
74HC3G14-Q100	0.5V _{CC}	0.5V _{CC}
74HCT3G14-Q100	1.3 V	1.3 V

Triple inverting Schmitt trigger

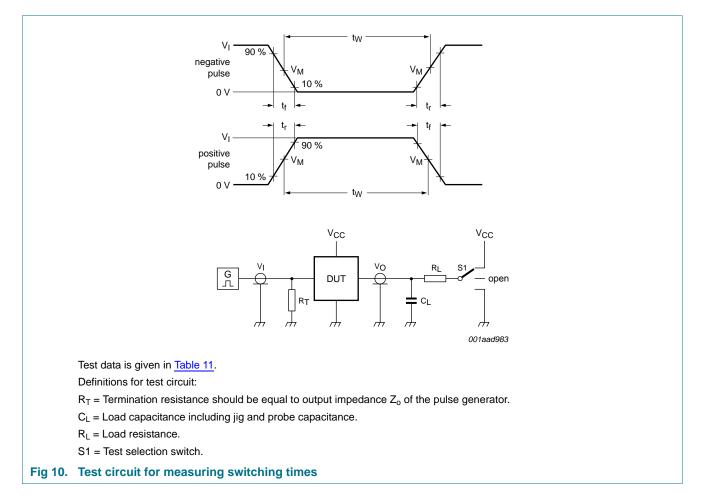


Table 11. Test data

Туре	Input		Load	S1 position	
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}
74HC3G14-Q100	GND to V_{CC}	≤ 6 ns	50 pF	1 kΩ	open
74HCT3G14-Q100	GND to 3.0 V	≤ 6 ns	50 pF	1 kΩ	open

14. Application information

The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

 P_{add} = additional power dissipation (μ W);

 $f_i = input frequency (MHz);$

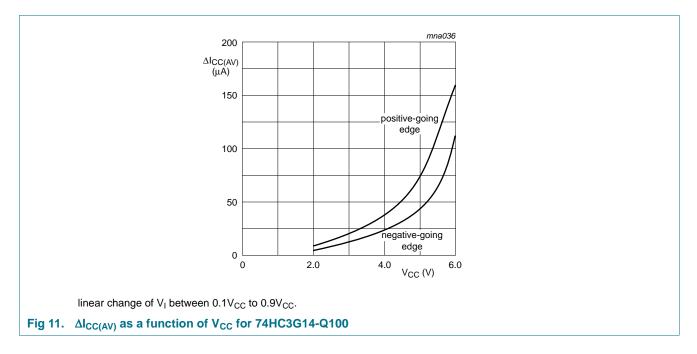
 t_r = input rise time (ns); 10 % to 90 %;

 t_f = input fall time (ns); 90 % to 10 %;

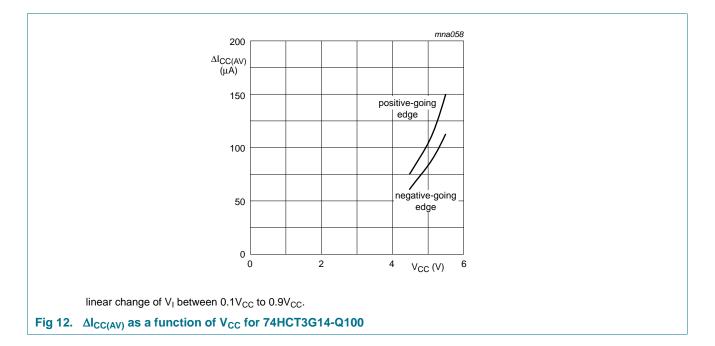
 $\Delta I_{CC(AV)}$ = average additional supply current (µA).

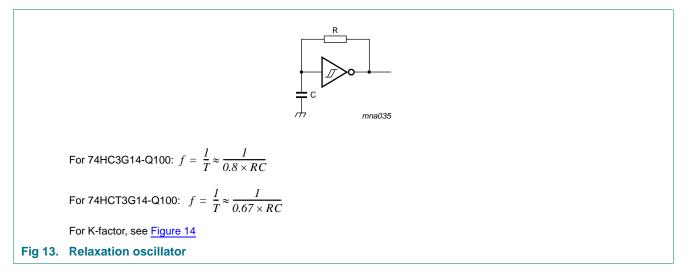
 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 11 and Figure 12.

An example of a relaxation circuit using the 74HC3G14-Q100/74HCT3G14-Q100 is shown in Figure 13.



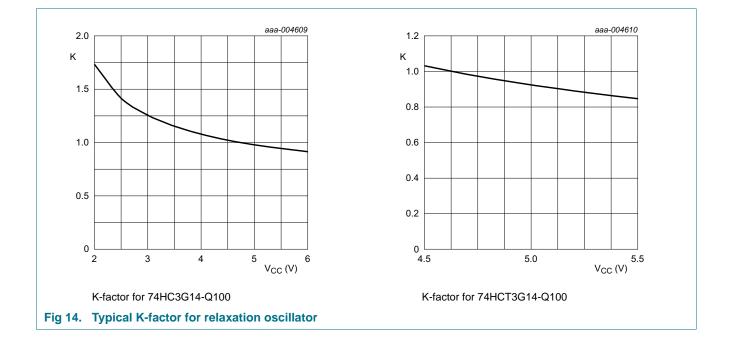
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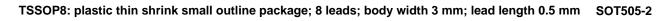
Triple inverting Schmitt trigger

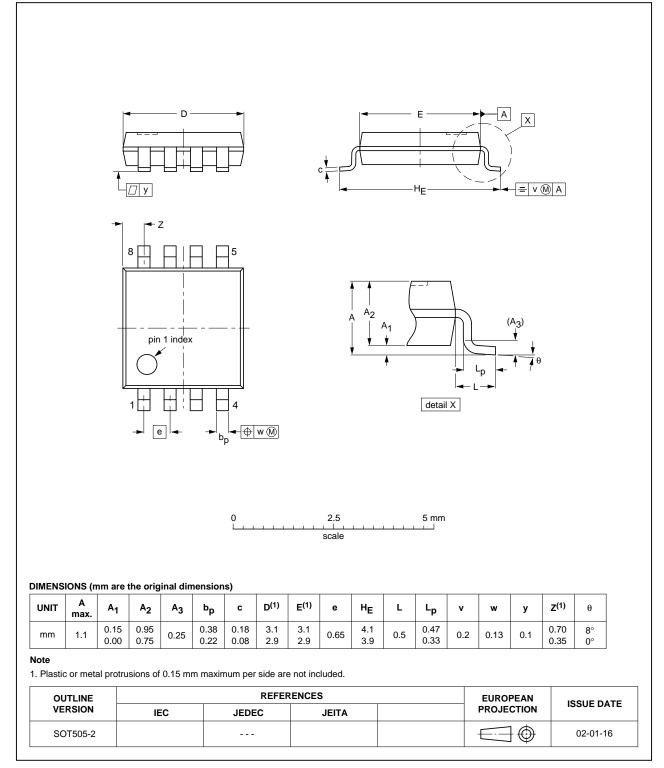


74HC_HCT3G14_Q100

Triple inverting Schmitt trigger

15. Package outline





74HC_HCT3G14_Q100

Triple inverting Schmitt trigger

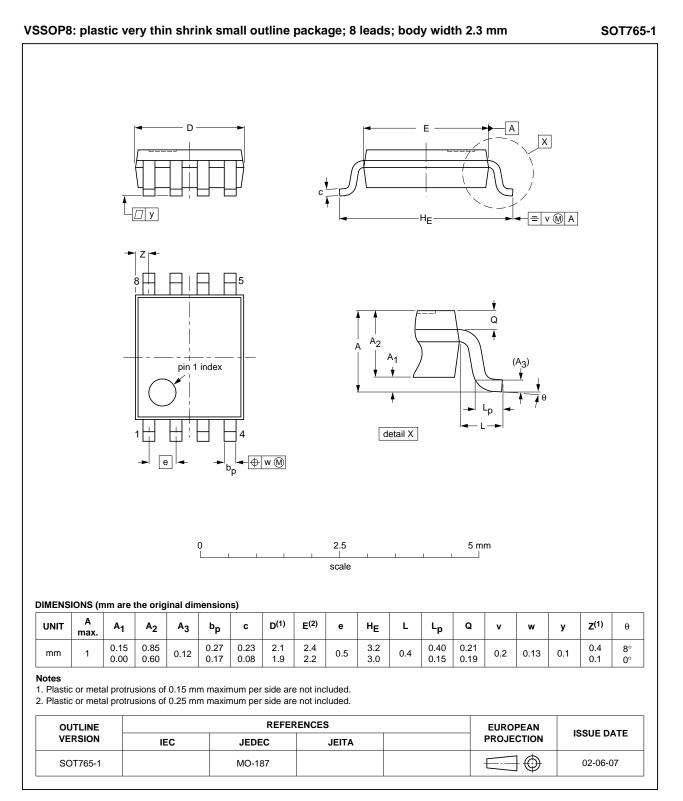


Fig 16. Package outline SOT765-1 (VSSOP8)

74HC_HCT3G14_Q100

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16. Abbreviations

Table 12.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model

17. Revision history

Table 13.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT3G14_Q100 v.2	20131209	Product data sheet	-	74HC_HCT3G14_Q100 v.1
Modifications: • Figure 14 added (typical K-factor for relaxation oscillator).				
74HC_HCT3G14_Q100 v.1	20131115	Product data sheet	-	-

18. Legal information

18.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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